

1 S 41		Si-Di	=1S40: 200V	34a	DO-1	BY 127	31a	BY 126...127, BY 133...134, 1N4003...07, ++
1 S 42		Si-Di	=1S40: 300V	34a	DO-1	BY 127	31a	BY 126...127, BY 133...134, 1N4004...07, ++
1 S 43		Si-Di	=1S40: 400V	34a	DO-1	BY 127	31a	BY 126...127, BY 133...134, 1N4004...07, ++
1 S 44		Si-Di	=1S40: 500V	34a	DO-1	BY 127	31a	BY 126...127, BY 133...134, 1N4005...07, ++
1 S 44 [Texas]	Fch, Tix	Si-Di	SS, 40V, 0,1A, <8ns	31a	DO-35	1N4148	31a	BA 318, BAY 38, 1N4148...49, 1N4151, ++
1 S 45		Si-Di	=1S40: 600V	34a	DO-1	BY 127	31a	BY 126...127, BY 133...134, 1N4005...07, ++
1 S 46		Si-Di	=1S40: 700V	34a	DO-1	BY 127	31a	BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 47		Si-Di	=1S40: 800V	34a	DO-1	BY 127	31a	BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 48	Tos	Si-Di	FM/VHF AFC	31a	DO-7			BA 111, BA 124, 1S2790, 1SV50, ++
1 S 49	Tos	Si-Di	FM/VHF AFC	31a	DO-7			BA 111, BA 124, 1S2790, 1SV50, ++
1 S 50	Tos	Ge-Di	Dem, 40V, 50mA	31a	DO-7			AA 113, AA 119, 1N34, 1N54, 1N60, ++
1 S 51	Tos	Z-Di	3,8...4,5V	=34a				BZW22/..., BZX61/..., ZPY..., 1N5915...25, ++
1 S 52		Z-Di	5,2...6,2V	=34a				
1 S 53		Z-Di	6,0...7,1V	=34a				
1 S 54		Z-Di	6,9...8,1V	=34a				
1 S 55		Z-Di	7,9...9,1V	=34a				
1 S 56		Z-Di	8,9...10,1V	=34a				
1 S 57	Tos	Si-Di		=34a				
1 S 58	Tos	Ge-Br	4x Di, Br, 75V, 30mA					
1 S 60	Son	Si-Di	Rr, Uni, 50V, 0,75A, Uf<1,2V(0,5A)	34	DO-1			BY 126...127, BY 133...135, 1N4001...07, ++
1 S 61		Si-Di	=1S60: 100V	34	DO-1			BY 126...127, BY 133...135, 1N4001...07, ++
1 S 62		Si-Di	=1S60: 200V	34	DO-1			BY 126...127, BY 133...134, 1N4002...07, ++
1 S 63		Si-Di	=1S60: 300V	34	DO-1			BY 126...127, BY 133...134, 1N4003...07, ++
1 S 64		Si-Di	=1S60: 400V	34	DO-1			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 65		Si-Di	=1S60: 500V	34	DO-1			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 66		Si-Di	=1S60: 600V	34	DO-1			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 71	Tos	Si-Di	Uni, 175V, 0,06A	31a	DO-7			BA 147/230, BA 190, 1N5195...96, ++
1 S 72	Tos	Si-Di	=1S71: 130V	31a	DO-7			BA 147/150, BA 189...190, 1N5195...96, ++
1 S 73(A)	Tos	Ge-Di	S, 20...30V, 0,12A, <900ns	31a	DO-7	(AA 138)	31a	AAY 49, AAZ 15, AAZ 17
1 S 74	Njr, Son	Ge-Di	Uni, 75V, 50mA	31a	DO-7			AA 117...118, AA 132...133
1 S 75	Njr, Son	Ge-Di	Uni, 30V, 25mA	31a	DO-7			AA 117...118, AA 132...133, 1N34, 1N34, 1N54, ++
1 S 76	Njr, Son	Ge-Di	Dem, 45V, 50mA	31a	DO-7			AA 113, AA 119, 1N34, 1N54, 1N60
1 S 77(H)	Hit	Ge-Di	S, 60V, 60mA	31a	DO-7	AA 133	31a	AA 117...118, AA 132...133, AAY 28
1 S 78(H)	Hit	Ge-Di	S, 40V, 80mA	31a	DO-7	AA 133	31a	AA 117...118, AA 132...133, AAY 49
1 S 79(H)	Hit	Ge-Di	S, 20V, 0,1A	31a	DO-7			AA 117...118, AA 132...133, AAY 49
1 S 80	Hit	Ge-Di	Dem, 30V, 40mA	31a	DO-7	AA 138	31a	AA 113, AA 119, 1N34, 1N54, 1N60, ++
1 S 81	Tos	Si-Di	Uni, 230V, 0,06A	31a	DO-7			BA 147/230, BA 157...159, BAY 21, ++
1 S 82	Tos	Ge-Di	Uni, 50V, 50mA	31a	DO-7			AA 117...118, AA 132...134, 1N34, 1N54, ++
1 S 83(H)	Hit	Ge-Di	Rr, Uni, 80V, 0,2A	2	TO-1	(AA 133)	31a	1N270
1 S 84(H)	Hit	Ge-Di	Rr, S, 200V, 0,1A	2	TO-1			1N39
1 S 85(H)	Hit	C-Di	AFC	31a	DO-7			BA 124...125, BB 119, 1S2790, 1SV50, ++
1 S 86	Tos	C-Di	FM/VHF AFC	31a	DO-7			BA 124...125, BB 119, 1S2790, 1SV50, ++
1 S 87	Tos	Ge-Di	S, 20V, 0,1A, <120ns	31a	DO-7			AAY 49, AAZ 15, AAZ 17
1 S 88		Ge-Di	=1S87: <240ns	31a	DO-7			AAY 49, AAZ 15, AAZ 17
1 S 89		Ge-Di	=1S87: <340ns	31a	DO-7			AAY 49, AAZ 15, AAZ 17
1 S 90	Tos	Si-Di	Rr, 150V, 0,3A, Uf<1,2V(0,5A)	34a	DO-1			BY 126...127, BY 133...135, 1N4003...07, ++
1 S 91		Si-Di	=1S90: 200V	34a	DO-1			BY 126...127, BY 133...134, 1N4003...07, ++
1 S 92		Si-Di	=1S90: 300V	34a	DO-1			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 93		Si-Di	=1S90: 400V	34a	DO-1			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 94		Si-Di	=1S90: 500V	34a	DO-1			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 95		Si-Di	=1S90: 600V	34a	DO-1			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 96		Si-Di	=1S90: 700V	34a	DO-1			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 97		Si-Di	=1S90: 800V	34a	DO-1			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 98		Si-Di	=1S90: 900V	34a	DO-1			BY 127, BY 133, BY 227, 1N4007, ++
1 S 99		Si-Di	=1S90: 1000V	34a	DO-1			BY 127, BY 133, BY 227, 1N4007, ++
1 S 90R...99R		Si-Di	=1S90...99:	34b	DO-1			-1S90...99
1 S 100	Tix, Tos	Si-Di	Rr, 150V, 0,75A, Uf<1,2V(0,75A)	34a	DO-1			BY 126...127, BY 133...135, 1N4003...07, ++
1 S 101		Si-Di	=1S100: 200V	34a	DO-1			BY 126...127, BY 133...134, 1N4003...07, ++
1 S 102		Si-Di	=1S100: 300V	34a	DO-1			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 103		Si-Di	=1S100: 400V	34a	DO-1			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 104		Si-Di	=1S100: 500V	34a	DO-1			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 105		Si-Di	=1S100: 600V	34a	DO-1			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 106		Si-Di	=1S100: 700V	34a	DO-1			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 107		Si-Di	=1S100: 800V	34a	DO-1			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 108		Si-Di	=1S100: 900V	34a	DO-1			BY 127, BY 133, BY 227, 1N4007, ++
1 S 109		Si-Di	=1S100: 1000V	34a	DO-1			BY 127, BY 133, BY 227, 1N4007, ++
1 S 100R...109R		Si-Di	=1S100...109:	34b	DO-1			+1S100...109
1 S 110	Tos	Si-Di	Dual, Rr, 500V, 0,4A					(2xBY 126...127, 2xBY 133...134, ++)
1 S 111 [Japan]	Nec	Si-Di	Rr, 100V, 0,75A, Uf<1,1V(0,5A)	34a	DO-1			BY 126...127, BY 133...135, 1N4002...07, ++
1 S 111 [Texas]	Tix	Si-Di	Rr, 225V, 0,4A, Uf<1V(0,2A)	31a	DO-7			BA 157...159, BY 204/4, 1N4004...07, ++
1 S 112 [Japan]	Nec	Si-Di	=1S111[Japan]: 200V	34a	DO-1			BY 126...127, BY 133...134, 1N4003...07, ++
1 S 112 [Texas]	Tix	Si-Di	=1S111[Texas]: 300V	31a	DO-7			BA 157...159, BY 204/4, 1N4004...07, ++
1 S 113 [Japan]	Nec	Si-Di	=1S111[Japan]: 300V	34a	DO-1			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 113 [Texas]	Tix	Si-Di	=1S111[Texas]: 400V	31a	DO-7			BA 157...159, BY 204/4, 1N4004...07, ++
1 S 114 [Japan]	Nec	Si-Di	=1S111[Japan]: 400V	34a	DO-1			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 115 [Japan]	Nec	Si-Di	=1S111[Japan]: 500V	34a	DO-1			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 115 [Texas]	Tix	Si-Di	=1S111[Texas]: 600V	31a	DO-7			BA 158...159, BY 204/8, 1N4005...07, ++
1 S 116 [Japan]	Nec	Si-Di	=1S111[Japan]: 600V	34a	DO-1			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 117 [Japan]	Nec	Si-Di	=1S111[Japan]: 700V	34a	DO-1			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 117 [Texas]	Tix	Si-Di	=1S111[Texas]: 800V	31a	DO-7			BA 159, BY 204/8, 1N4006...07, ++
1 S 118 [Japan]	Nec	Si-Di	=1S111[Japan]: 800V	34a	DO-1			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 119 [Japan]	Nec	Si-Di	=1S111[Japan]: 50V	34a	DO-1			BY 126...127, BY 133...135, 1N4001...07, ++
1 S 120 [Japan]	Nec	Si-Di	Rr, 50V, 0,6A, Uf<1,2V(0,5A)	34a	DO-1			BY 126...127, BY 133...135, 1N4001...07, ++
1 S 120 [Texas]	Tix	Si-Di	Rr, 50V, 0,2A, Uf<1V(0,5A)	31a	DO-7			BA 157...159, BY 204/4, BY 206...207, ++
1 S 121 [Japan]	Nec	Si-Di	=1S120[Japan]: 100V	34a	DO-1			BY 126...127, BY 133...135, 1N4002...07, ++
1 S 121 [Texas]	Tix	Si-Di	=1S120[Texas]: 150V	31a	DO-7			BA 157...159, BY 204/4, BY 206...207, ++
1 S 122 [Japan]	Nec	Si-Di	=1S120[Japan]: 200V	34a	DO-1			BY 126...127, BY 133...134, 1N4003...07, ++
1 S 123 [Japan]		Si-Di	=1S120[Japan]: 300V	34a	DO-1			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 124 [Japan]		Si-Di	=1S120[Japan]: 400V	34a	DO-1			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 125 [Japan]		Si-Di	=1S120[Japan]: 500V	34a	DO-1			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 126 [Japan]		Si-Di	=1S120[Japan]: 600V	34a	DO-1			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 127	Tos	Ge-Di	Uni, 75V, 30mA	31	DO-7			AA 117...118, AA 132...133, 1N634
1 S 128	Tos	Ge-Di	S, 6V, <25ns	31a	DO-7			AAY 48, 1N995